

Hexagonal high
electrical resistivity,
excellent dielectric
losses,

[Psychology](#), [Behaviorism](#)



Hexagonal ferrite materials are metal oxides that exhibit high saturation magnetization, high/low coercivity, high electrical resistivity, excellent dielectric losses, high permittivity and permeability. Hexa-ferrites are very attractive materials for technological applications due to their unique electrical and magnetic properties. Hexagonal ferrites have many applications, such as recording, magneto-optical devices, and permanent magnets. Its unique magneto-dielectric property is particularly interesting in microwave and radio frequency applications. Dielectric characteristic is an important property of hexagonal ferrites which depends on different factors like polarization, sintering temperature and time, frequency, method of preparation, and kind of charge carrier. Composition, temperature and substituted or doped badly effect the electrical properties of hexagonal ferrites. So, a little change in composition, can transform material from insulator to semiconductor.

Hexagonal ferrites are of different types i. e. (SrFe₁₂O₁₉), W(SrM₂Fe₁₆O₂₇), X(Sr₂M₂Fe₂₈O₄₆), Y(Sr₂M₂Fe₁₂O₂₂), Z(Sr₃M₂Fe₂₄O₄₁), U(Sr₄M₂Fe₃₆O₆₀), and R(SrM₂Fe₄O₁₁)¹⁰. where M = a small 2+ ion such as cobalt, nickel or zinc. R-type hexagonal ferrites have hexagonal structure and represented as RR* where R is R block and R* has the phase shift of 180°. There are a lot of methods to synthesize but sol-gel is low cost and easy method. Therefore, sol-gel technique is used to synthesize the single phase of R-type hexagonal (SrM₂Fe₄O₁₁) where 'M' is tetravalent element. The need of using tetravalent element is to maintain the overall neutrality of the sample.

Maria et al synthesized strontium-barium X-type hexagonal ferrites with composition $\text{SrBaCu}_{2-x}\text{Ni}_x\text{Nd}_y\text{Fe}_{28-y}\text{O}_{46}$ ($x = 0, 0.2, 0.4, 0.6, 0.8, 1$ and $y = 0, 0.02, 0.$

$0.04, 0.06, 0.08, 0.1$) by sol-gel method. The XRD analysis reveals the single phase for all the samples. Doping of Nd-Ni, the trend of dielectric constant, dielectric loss and AC-conductivity showed decreasing.

The Cole-Cole plots revealed grain boundary contribution. The appearance of single semi-circle in impedance, the exceptional role of grain boundaries in the conduction process confirmed by Cole-Cole graphs. The lower dielectric parameters of studied nano X-type ferrites propose their possibility for high-frequency applications i.

e. phase shifters, dielectric resonators, etc. Long et al synthesized Sr-hexaferrites with series of $\text{Sr}_{1-x}\text{La}_x\text{Fe}_{12-x}\text{Zn}_x\text{O}_{19}$ ($x = 0-0.3$) with Bi_2O_3 chemical by microwave sintering method at low sintering temperatures. In this work, crystal structure, magnetic, electrical, and dielectric properties were studied.

These properties indicate that the La^{3+} - Zn^{2+} ions can partially substitute the Sr^{2+} - Fe^{3+} ions with $x = 0.2$ for the low temperature sintered $\text{Sr}_{1-x}\text{La}_x\text{Fe}_{12-x}\text{Zn}_x\text{O}_{19}$ ($x = 0-0.3$) hexa-ferrites. The dielectric behavior of the $\text{Sr}_{1-x}\text{La}_x\text{Fe}_{12-x}\text{Zn}_x\text{O}_{19}$ ($x = 0-0.2$) ferrites is found to obey the space charge polarization mechanism from the typical current-voltage (I-V) curves and polarization versus electric field (P-E) loop.